FAIRCHILD SEMICONDUCTOR®

January 2009

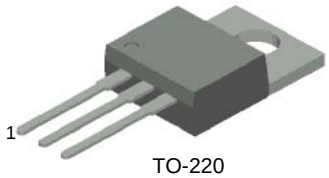
FJP5200
NPN Epitaxial Silicon Transistor

Applications

- High-Fidelity Audio Output Amplifier
- General Purpose Power Amplifier

Features

- High Current Capability: I_C = 17A.
- High Power Dissipation : 80watts.
- High Frequency : 30MHz.
- High Voltage : V_{CEO}=250V
- Wide S.O.A for reliable operation.
- Excellent Gain Linearity for low THD.
- Complement to FJP1943
- Thermal and electrical Spice models are available.
- Same transistor is also available in:
  -- TO264 package, 2SC5200/FJL4315 : 150 watts
  -- TO3P package, 2SC5242/FJA4313 : 130 watts
  -- TO220F package, FJPF5200 : 50 watts



TO-220

1.Base 2.Collector 3.Emitter

Absolute Maximum Ratings* T_a = 25°C unless otherwise noted

Symbol	Parameter	Ratings	Units
BV_{CBO}	Collector-Base Voltage	250	V
BV_{CEO}	Collector-Emitter Voltage	250	V
BV_{EBO}	Emitter-Base Voltage	5	V
I_C	Collector Current(DC)	17	A
I_B	Base Current	1.5	A
P_D	Total Device Dissipation(T_C=25°C) Derate above 25°C	80 0.64	W W/°C
T_J, T_{STG}	Junction and Storage Temperature	- 50 ~ +150	°C

* These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

Thermal Characteristics* T_a=25°C unless otherwise noted

Symbol	Parameter	Max.	Units
$R_{\theta JC}$	Thermal Resistance, Junction to Case	1.25	°C/W

* Device mounted on minimum pad size

h_{FE} Classification

Classification	R	O
h_{FE1}	55 ~ 110	80 ~ 160

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Electrical Characteristics* T_a=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
BV_{CBO}	Collector-Base Breakdown Voltage	I_C=5mA, I_E=0	250			V
BV_{CEO}	Collector-Emitter Breakdown Voltage	I_C=10mA, R_{BE}=∞	250			V
BV_{EBO}	Emitter-Base Breakdown Voltage	I_E=5mA, I_C=0	5			V
I_{CBO}	Collector Cut-off Current	V_{CB}=230V, I_E=0			5.0	μA
I_{EBO}	Emitter Cut-off Current	V_{EB}=5V, I_C=0			5.0	μA
h_{FE1}	DC Current Gain	V_{CE}=5V, I_C=1A	55		160	
h_{FE2}	DC Current Gain	V_{CE}=5V, I_C=7A	35	60		
V_{CE}(sat)	Collector-Emitter Saturation Voltage	I_C=8A, I_B=0.8A		0.4	3.0	V
V_{BE}(on)	Base-Emitter On Voltage	V_{CE}=5V, I_C=7A		1.0	1.5	V
f_T	Current Gain Bandwidth Product	V_{CE}=5V, I_C=1A		30		MHz
C_{ob}	Output Capacitance	V_{CB}=10V, f=1MHz		200		pF

* Pulse Test: Pulse Widt=20μs, Duty Cycle≤2%

Ordering Information

Part Number	Marking	Package	Packing Method	Remarks
FJP5200RTU	J5200R	TO-220	TUBE	hFE1 R grade
FJP5200OTU	J5200O	TO-220	TUBE	hFE1 O grade

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Typical Characteristics

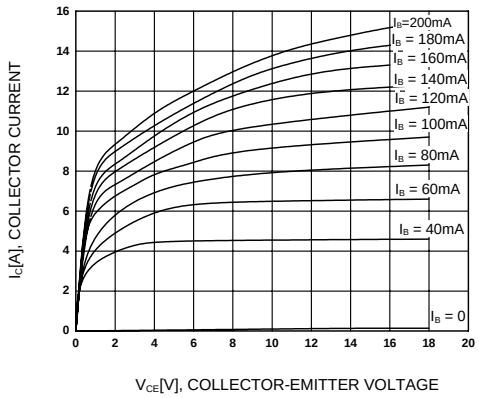


Figure 1. Static Characteristic

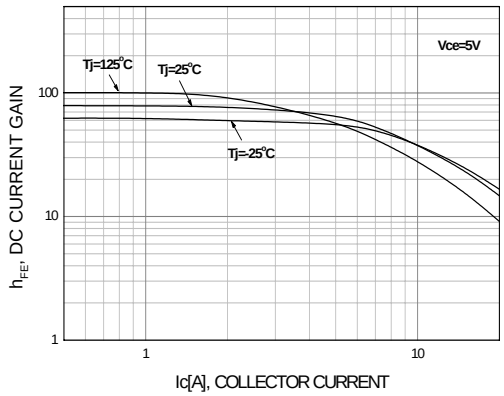


Figure 2. DC current Gain (R grade)

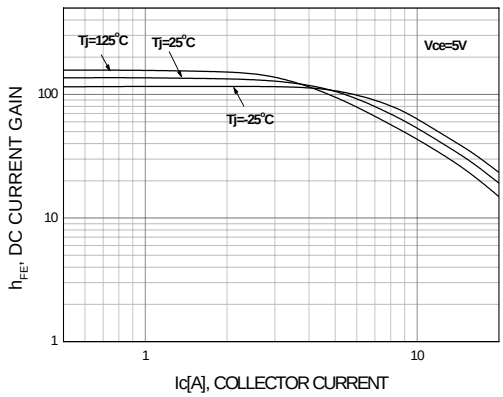


Figure 3. DC current Gain (O grade)

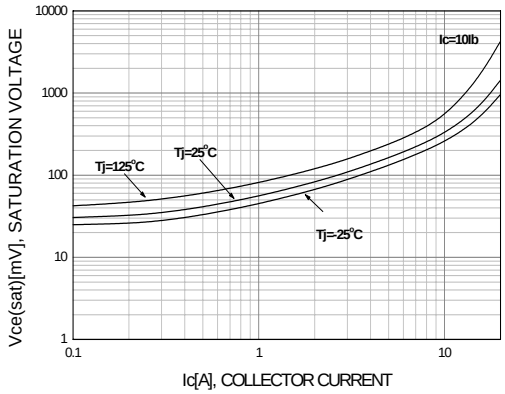


Figure 4. Collector-Emitter Saturation Voltage



Figure 5. Base-Emitter Saturation Voltage

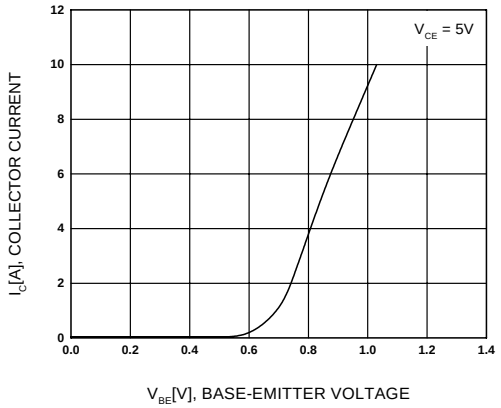


Figure 6. Base-Emitter On Voltage

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Typical Characteristics

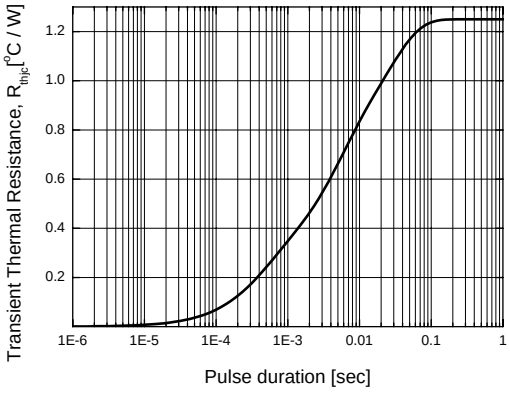


Figure 7. Thermal Resistance

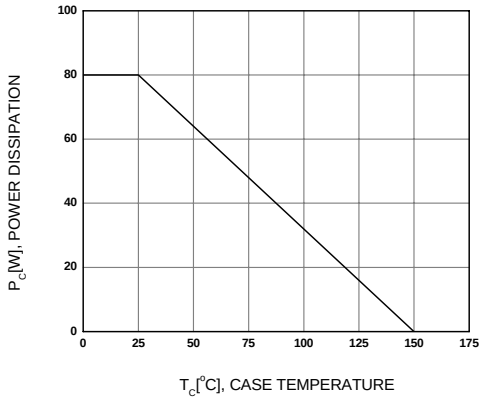
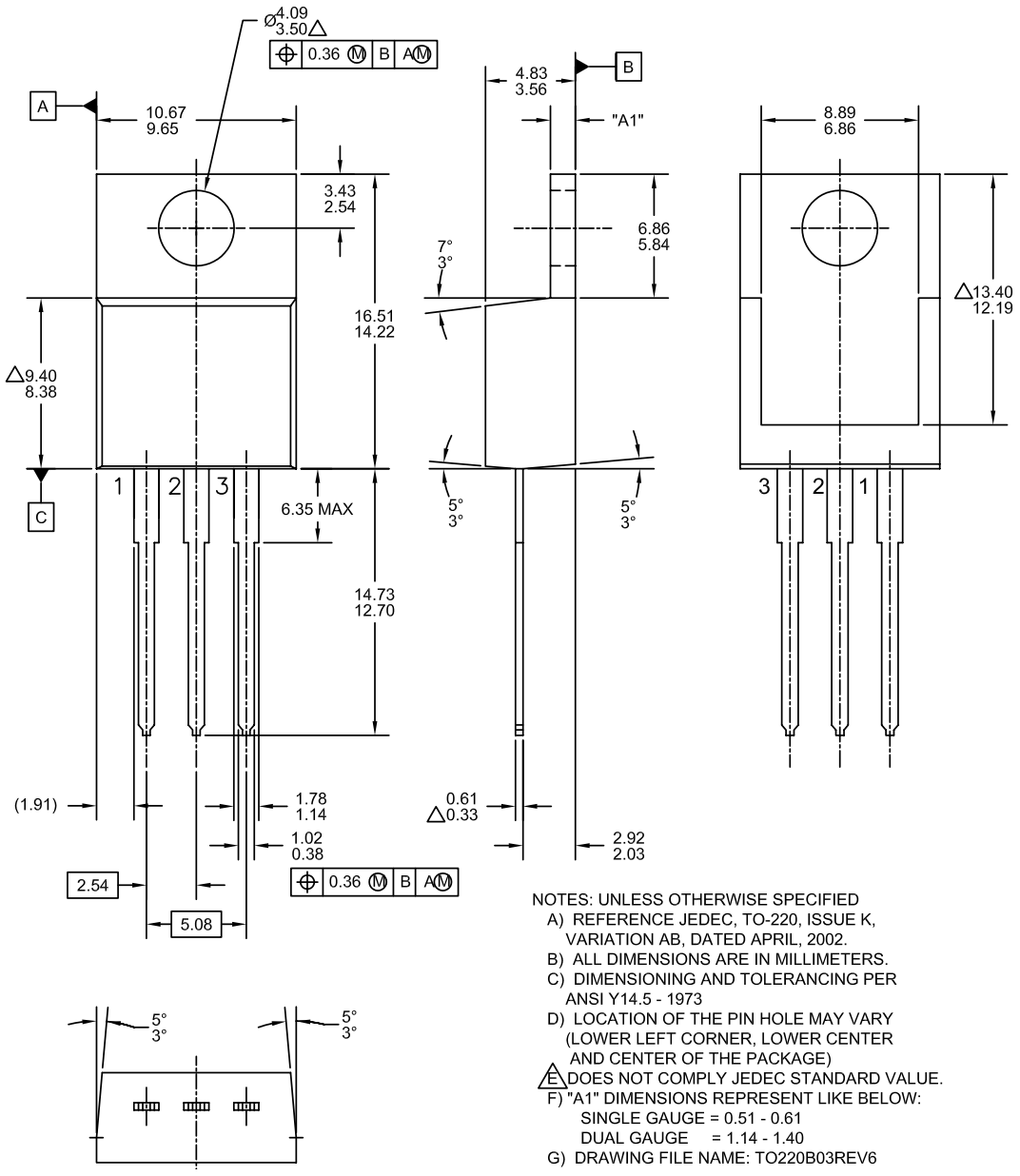


Figure 8. Power Derating

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Mechanical Dimensions

TO220



NOTES: UNLESS OTHERWISE SPECIFIED

A) REFERENCE JEDEC, TO-220, ISSUE K, VARIATION AB, DATED APRIL, 2002.

B) ALL DIMENSIONS ARE IN MILLIMETERS.

C) DIMENSIONING AND TOLERANCING PER ANSI Y14.5 - 1973

D) LOCATION OF THE PIN HOLE MAY VARY (LOWER LEFT CORNER, LOWER CENTER AND CENTER OF THE PACKAGE)

△E DOES NOT COMPLY JEDEC STANDARD VALUE.

F) "A1" DIMENSIONS REPRESENT LIKE BELOW:
SINGLE GAUGE = 0.51 - 0.61
DUAL GAUGE = 1.14 - 1.40

G) DRAWING FILE NAME: TO220B03REV6

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Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.
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